

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Graphene and related two-dimensional materials: Structure-property relationships for electronics and optoelectronics. Applied Physics Reviews, 2017, 4, .	5.5	476
2	Atomristor: Nonvolatile Resistance Switching in Atomic Sheets of Transition Metal Dichalcogenides. Nano Letters, 2018, 18, 434-441.	4.5	375
3	Synergistic Effects of Plasmonics and Electron Trapping in Graphene Short-Wave Infrared Photodetectors with Ultrahigh Responsivity. ACS Nano, 2017, 11, 430-437.	7.3	192
4	1T′ Transition Metal Telluride Atomic Layers for Plasmon-Free SERS at Femtomolar Levels. Journal of the American Chemical Society, 2018, 140, 8696-8704.	6.6	192
5	Centimeter-Scale CVD Growth of Highly Crystalline Single-Layer MoS ₂ Film with Spatial Homogeneity and the Visualization of Grain Boundaries. ACS Applied Materials & Interfaces, 2017, 9, 12073-12081.	4.0	120
6	Graphene controlled Brewster angle device for ultra broadband terahertz modulation. Nature Communications, 2018, 9, 4909.	5.8	117
7	Hybrid graphene tunneling photoconductor with interface engineering towards fast photoresponse and high responsivity. Npj 2D Materials and Applications, 2017, 1, .	3.9	77
8	Investigation of Na3V2(PO4)2O2F as a sodium ion battery cathode material: Influences of morphology and voltage window. Nano Energy, 2019, 60, 510-519.	8.2	69
9	Restoring the photovoltaic effect in graphene-based van der Waals heterojunctions towards self-powered high-detectivity photodetectors. Nano Energy, 2019, 57, 214-221.	8.2	65
10	Enhancing lightâ€matter interaction in <scp>2D</scp> materials by optical micro/nano architectures for highâ€performance optoelectronic devices. InformaÄnÃ-MateriAįly, 2021, 3, 36-60.	8.5	59
11	Modification on Single-Layer Graphene Induced by Low-Energy Electron-Beam Irradiation. Journal of Physical Chemistry C, 2013, 117, 10079-10085.	1.5	43
12	Thicknessâ€Dependent Optical Properties and Inâ€Plane Anisotropic Raman Response of the 2D βâ€In 2 S 3. Advanced Optical Materials, 2019, 7, 1901085.	3.6	39
13	High-Quality Monolithic Graphene Films via Laterally Stitched Growth and Structural Repair of Isolated Flakes for Transparent Electronics. Chemistry of Materials, 2017, 29, 7808-7815.	3.2	38
14	Graphene-on-silicon nitride waveguide photodetector with interdigital contacts. Applied Physics Letters, 2018, 112, 211107.	1.5	37
15	Graphene/In ₂ S ₃ van der Waals Heterostructure for Ultrasensitive Photodetection. ACS Photonics, 2018, 5, 4912-4919.	3.2	36
16	Nax(Cu–Fe–Mn)O2 system as cathode materials for Na-ion batteries. Nano Energy, 2020, 78, 105142.	8.2	29
17	Efficient Electronic Transport in Partially Disordered Co ₃ O ₄ Nanosheets for Electrocatalytic Oxygen Evolution Reaction. ACS Applied Energy Materials, 2020, 3, 3071-3081.	2.5	27
18	Deterministic and Etchingâ€Free Transfer of Largeâ€Scale 2D Layered Materials for Constructing Interlayer Coupled van der Waals Heterostructures. Advanced Materials Technologies, 2018, 3, 1700282.	3.0	26

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19	Enhanced four-wave mixing with MoS ₂ on a silicon waveguide. Journal of Optics (United) Tj ETQq1 1	0.784314 1.0	rgBT /Over
20	Large-area ReS2 monolayer films on flexible substrate for SERS based molecular sensing with strong fluorescence quenching. Applied Surface Science, 2021, 542, 148757.	3.1	17
21	Efficient passivation of monolayer MoS2 by epitaxially grown 2D organic crystals. Science Bulletin, 2019, 64, 1700-1706.	4.3	15
22	Intrinsic memristive mechanisms in 2D layered materials for high-performance memory. Journal of Applied Physics, 2021, 129, .	1.1	15
23	Ultraâ€Narrowband Photodetector with High Responsivity Enabled by Integrating Monolayer Jâ€Aggregate Organic Crystal with Graphene. Advanced Optical Materials, 2021, 9, 2100158.	3.6	15
24	Controlled Synthesis of MoxW1–xTe2 Atomic Layers with Emergent Quantum States. ACS Nano, 2021, 15, 11526-11534.	7.3	12
25	Enhanced Raman scattering on two-dimensional palladium diselenide. Nanoscale, 2022, 14, 4181-4187.	2.8	12
26	A spontaneously formed plasmonic-MoTe2 hybrid platform for ultrasensitive Raman enhancement. Cell Reports Physical Science, 2021, 2, 100526.	2.8	10
27	Defect Etching of Phaseâ€Transitionâ€Assisted CVDâ€Grown 2Hâ€MoTe ₂ . Small, 2021, 17, e21021	4 6. 2	9
28	Phase-controlled epitaxial growth of MoTe2: Approaching high-quality 2D materials for electronic devices with low contact resistance. Journal of Applied Physics, 2022, 131, .	1.1	9
29	Enhanced Photoresponse in Interfacial Gated Graphene Phototransistor With Ultrathin Al ₂ O ₃ Dielectric. IEEE Electron Device Letters, 2018, 39, 987-990.	2.2	8
30	Observation of Strong <i>J</i> -Aggregate Light Emission in Monolayer Molecular Crystal on Hexagonal Boron Nitride. Journal of Physical Chemistry A, 2020, 124, 7340-7345.	1.1	8
31	Enhanced thermo-optic nonlinearities in a MoS ₂ -on-silicon microring resonator. Applied Physics Express, 2020, 13, 022004.	1.1	8
32	Experimental Observation of Ultrahigh Mobility Anisotropy of Organic Semiconductors in the Two-Dimensional Limit. ACS Applied Electronic Materials, 2020, 2, 2888-2894.	2.0	6
33	Investigation on the Fano-Type Asymmetry in Atomic Semiconductor Coupled to the Plasmonic Lattice. ACS Photonics, 2021, 8, 3583-3590.	3.2	6
34	Preparation and Characterization of Two-Dimensional Layered Transition Metal Dichalcogenide Thin Films. , 2019, , .		0